

R07DS0313EJ1000 (Previous: REJ03G0841-0900) Rev.10.00 Mar 28, 2011

Features

- Small SMD package CMPAK-6 built in twin BBFET; To reduce using parts cost & PC board space.
- Suitable for World Standard Tuner RF amplifier.
- Very useful for total tuner cost reduction.
- Withstanding to ESD; Built in ESD absorbing diode. Withstand up to 200 V at C = 200 pF, Rs = 0 conditions.
- Provide mini mold packages; CMPAK-6

Outline

RENESAS Package code: PTSP0006JA-A (Package name: CMPAK-6)



1. Gate-1(1) 2. Source 3. Drain(1) 4. Drain(2) 5. Gate-2 6. Gate-1(2)

Notes: 1. Marking is "BM".

2. TBB1002 is individual type number of RENESAS TWIN BBFET.

Absolute Maximum Ratings

 $(Ta = 25^{\circ}C)$ Item Symbol Ratings Unit Drain to source voltage VDS 6 V Gate1 to source voltage V_{G1S} +6 V -0 V_{G2S} +6 V Gate2 to source voltage -0 30 Drain current I_D mΑ Pch Channel power dissipation 250 mW Tch 150 °C Channel temperature Storage temperature Tstg -55 to +150 °C

Notes: 3. Value on the glass epoxy board ($49mm \times 38mm \times 1mm$).

Electrical Characteristics

The below specification are applicable for UHF unit (FET1)

						$(Ta = 25^{\circ}C)$
Item	Symbol	Min	Тур	Max	Unit	Test conditions
Drain to source breakdown voltage	V _{(BR)DSS}	6	_	_	V	$I_D = 200 \ \mu A, \ V_{G1S} = V_{G2S} = 0$
Gate1 to source breakdown voltage	V _{(BR)G1SS}	+6	_	_	V	I_{G1} = +10 μ A, V_{G2S} = V_{DS} = 0
Gate2 to source breakdown voltage	V _{(BR)G2SS}	+6	_	—	V	I_{G2} = +10 μ A, V_{G1S} = V_{DS} = 0
Gate1 to source cutoff current	I _{G1SS}	—	_	+100	nA	$V_{G1S} = +5 V, V_{G2S} = V_{DS} = 0$
Gate2 to source cutoff current	I _{G2SS}	—	_	+100	nA	$V_{G2S} = +5 V, V_{G1S} = V_{DS} = 0$
Gate1 to source cutoff voltage	V _{G1S(off)}	0.5	0.75	1.0	V	$V_{DS} = 5 V$, $V_{G2S} = 4 V$
						I _D = 100 μA
Gate2 to source cutoff voltage	V _{G2S(off)}	0.5	0.75	1.0	V	$V_{DS} = 5 \text{ V}, V_{G1S} = 5 \text{ V}$
						I _D = 100 μA
Drain current	I _{D(op)}	13	17	21	mA	$V_{DS} = 5 V, V_{G1} = 5 V$
						V_{G2S} = 4 V, R_G = 100 k Ω
Forward transfer admittance	y _{fs}	21	26	31	mS	$V_{DS} = 5 V, V_{G1} = 5 V, V_{G2S} = 4 V$
						$R_G = 100 \text{ k}\Omega$, f = 1 kHz
Input capacitance	Ciss	1.4	1.8	2.2	pF	$V_{DS} = 5 V, V_{G1} = 5 V$
Output capacitance	Coss	1.0	1.4	1.8	pF	V_{G2S} = 4 V, R_G = 100 k Ω
Reverse transfer capacitance	Crss	—	0.02	0.04	pF	f = 1 MHz
Power gain	PG	16	21	—	dB	$V_{DS} = V_{G1} = 5 V, V_{G2S} = 4 V$
Noise figure	NF	_	1.7	2.5	dB	$R_G = 100 \text{ k}\Omega$, f = 900 MHz
						Zi =S11*, Zo=S22*(:PG)
						Zi =S11opt (:NF)

The below specification are applicable for VHF unit (FET2)

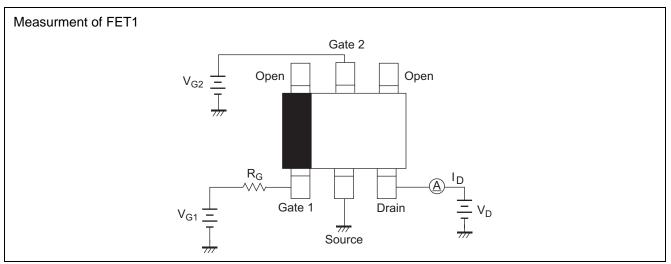
					-	$(Ta = 25^{\circ}C)$
Item	Symbol	Min	Тур	Max	Unit	Test conditions
Drain to source breakdown voltage	V _{(BR)DSS}	6	—	—	V	$I_D = 200 \ \mu A, \ V_{G1S} = V_{G2S} = 0$
Gate1 to source breakdown voltage	V _{(BR)G1SS}	+6	—	_	V	$I_{G1} = +10 \ \mu A, \ V_{G2S} = V_{DS} = 0$
Gate2 to source breakdown voltage	V _{(BR)G2SS}	+6	—	—	V	I_{G2} = +10 μ A, V_{G1S} = V_{DS} = 0
Gate1 to source cutoff current	I _{G1SS}	_	—	+100	nA	$V_{G1S} = +5 V, V_{G2S} = V_{DS} = 0$
Gate2 to source cutoff current	I _{G2SS}	_	—	+100	nA	$V_{G2S} = +5 V, V_{G1S} = V_{DS} = 0$
Gate1 to source cutoff voltage	V _{G1S(off)}	0.5	0.75	1.0	V	$V_{DS} = 5 V, V_{G2S} = 4 V$
						I _D = 100 μA
Gate2 to source cutoff voltage	V _{G2S(off)}	0.5	0.75	1.0	V	$V_{DS} = 5 V, V_{G1S} = 5 V$
						I _D = 100 μA
Drain current	I _{D(op)}	14	18	22	mA	$V_{DS} = 5V, V_{G1} = 5 V, V_{G2S} = 4 V$
						$R_G = 82 \text{ k}\Omega$
Forward transfer admittance	y _{fs}	20	25	30	mS	$V_{DS} = 5 V, V_{G1} = 5 V$
						V_{G2S} = 4 V, R_G = 82 k Ω
						f = 1 kHz
Input capacitance	Ciss	2.2	2.6	3.0	pF	$V_{DS} = 5 V, V_{G1} = 5 V$
Output capacitance	Coss	1.2	1.6	2.0	pF	V_{G2S} =4 V, R_G = 82 k Ω
Reverse transfer capacitance	Crss		0.03	0.05	pF	f = 1 MHz
Power gain	PG	22	27		dB	$V_{DS} = V_{G1} = 5 V, V_{G2S} = 4 V$
Noise figure	NF		1.2	1.7	dB	$R_{G} = 82 \text{ k}\Omega, \text{ f} = 200 \text{ MHz}$

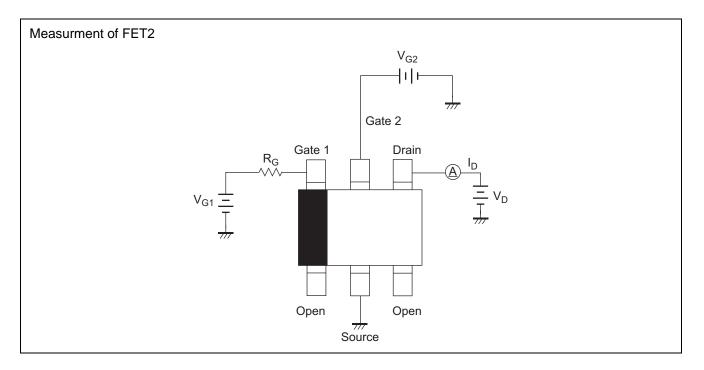
 $(Ta = 25^{\circ}C)$



Test Circuits

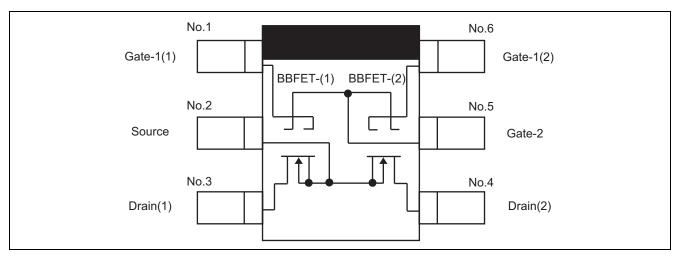
• DC Biasing Circuit for Operating Characteristic Items (I_{D(op)}, |yfs|, Ciss, Coss, Crss, NF, PG)



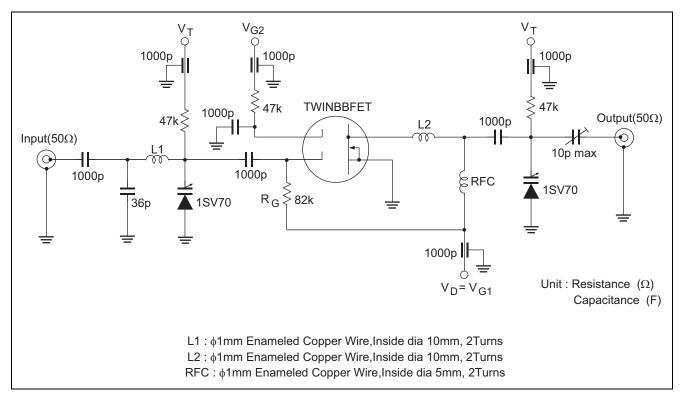




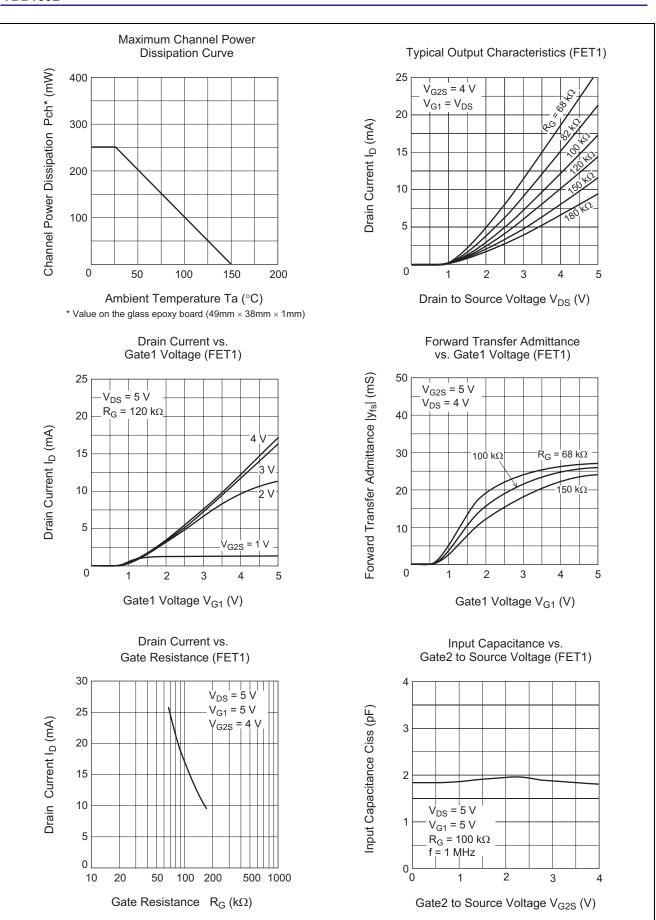
• Equivalent Circuit



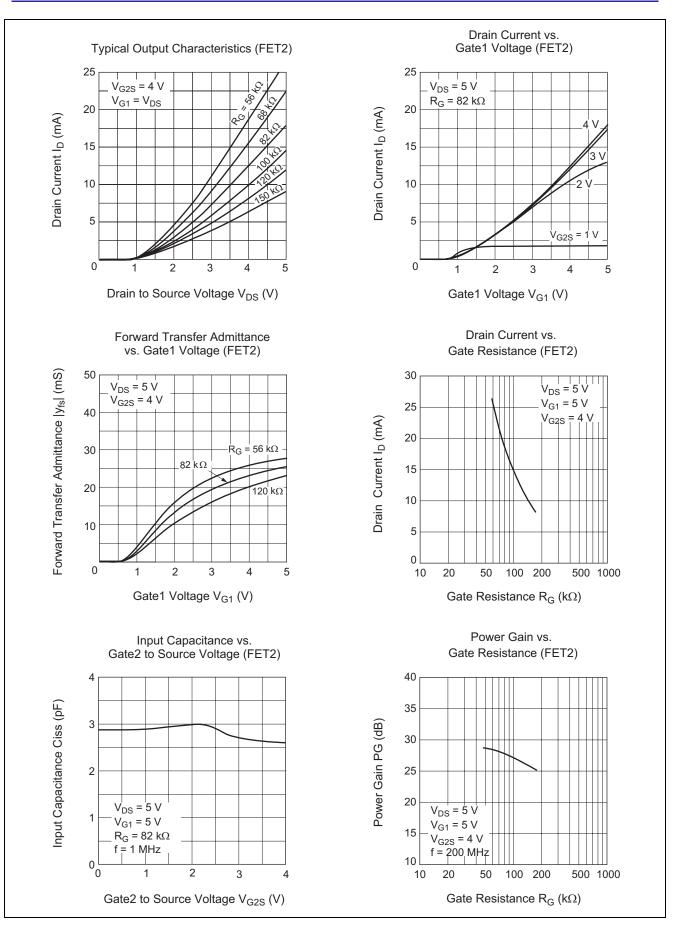
• 200 MHz Power Gain, Noise Figure Test Circuit

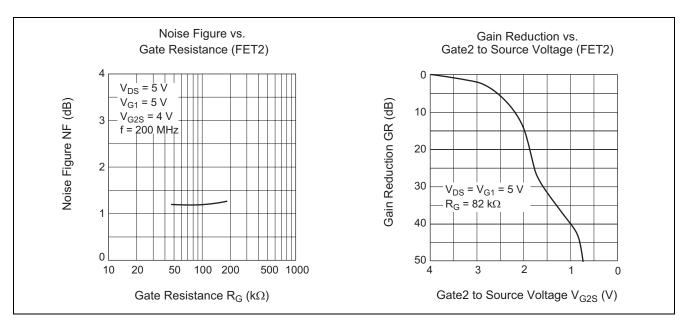






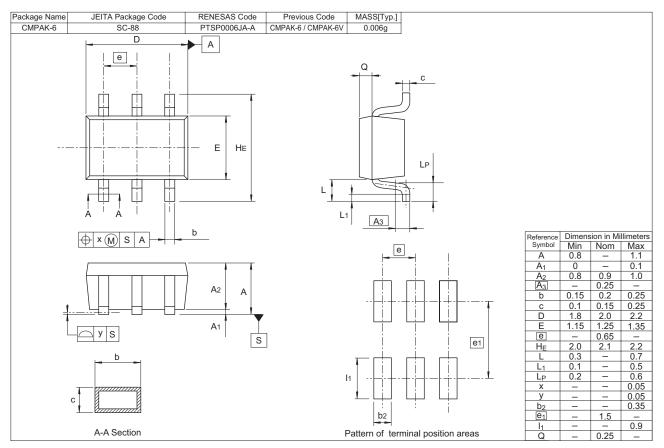








Package Dimensions



Ordering Information

Orderable Part Number	Quantity	Shipping Container
TBB1002BMTL-E	3000	φ 178 mm Reel, 8 mm Emboss Taping
TBB1002BMTL-H		

Note: For some grades, production may be terminated. Please contact the Renesas sales office to check the state of production before ordering the product.



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